

# Rogers Electronic Tubes & Components

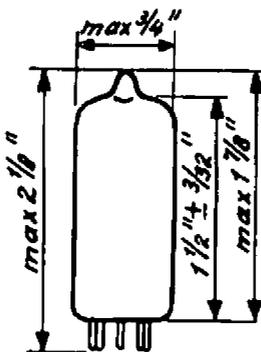
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Description: Pentode with variable transconductance for use as R.F. amplifier, I.F. amplifier or mixer in carradio sets, to be operated directly from a storage battery

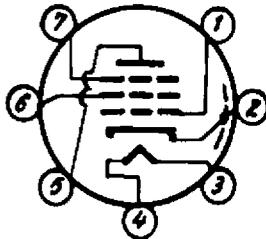
## Mechanical data

Cathode	coated unipotential
Base	E 7-1
Bulb	T 5 <sup>1</sup> / <sub>2</sub>
Outline	5 - 2
Basing designation	7 EN
Mounting position	any

## TUBE OUTLINE



## BOTTOM VIEW OF BASE



## BASE PIN No.

1	Grid No. 1
2	Cathode, internal shield
3	Heater
4	Heater
5	Plate
6	Grid No. 2
7	Grid No. 3

## ELEMENT

## Heater data

Heater voltage	6.3 volts
Heater current	300 mamps

## Direct interelectrode capacitances

Grid No. 1 to all other elements except plate	6.5 μμF
Plate to all other elements except grid No. 1	4.0 μμF
Plate to grid No. 1	0.015 μμF
Grid No. 1 to grid No. 2	3.0 μμF

Maximum ratings (design center values)

Plate voltage	50 volts max.
Plate dissipation	0.5 watt max.
Grid No. 2 voltage	50 volts max.
Grid No. 2 dissipation	0.5 watt max.
Grid No. 3 voltage	50 volts max.
Cathode current	15 mamps max.
Grid No. 1 circuit resistance	22 megohm max
Grid No. 3 circuit resistance	5 megohm max
Voltage between cathode and heater	50 volts max.

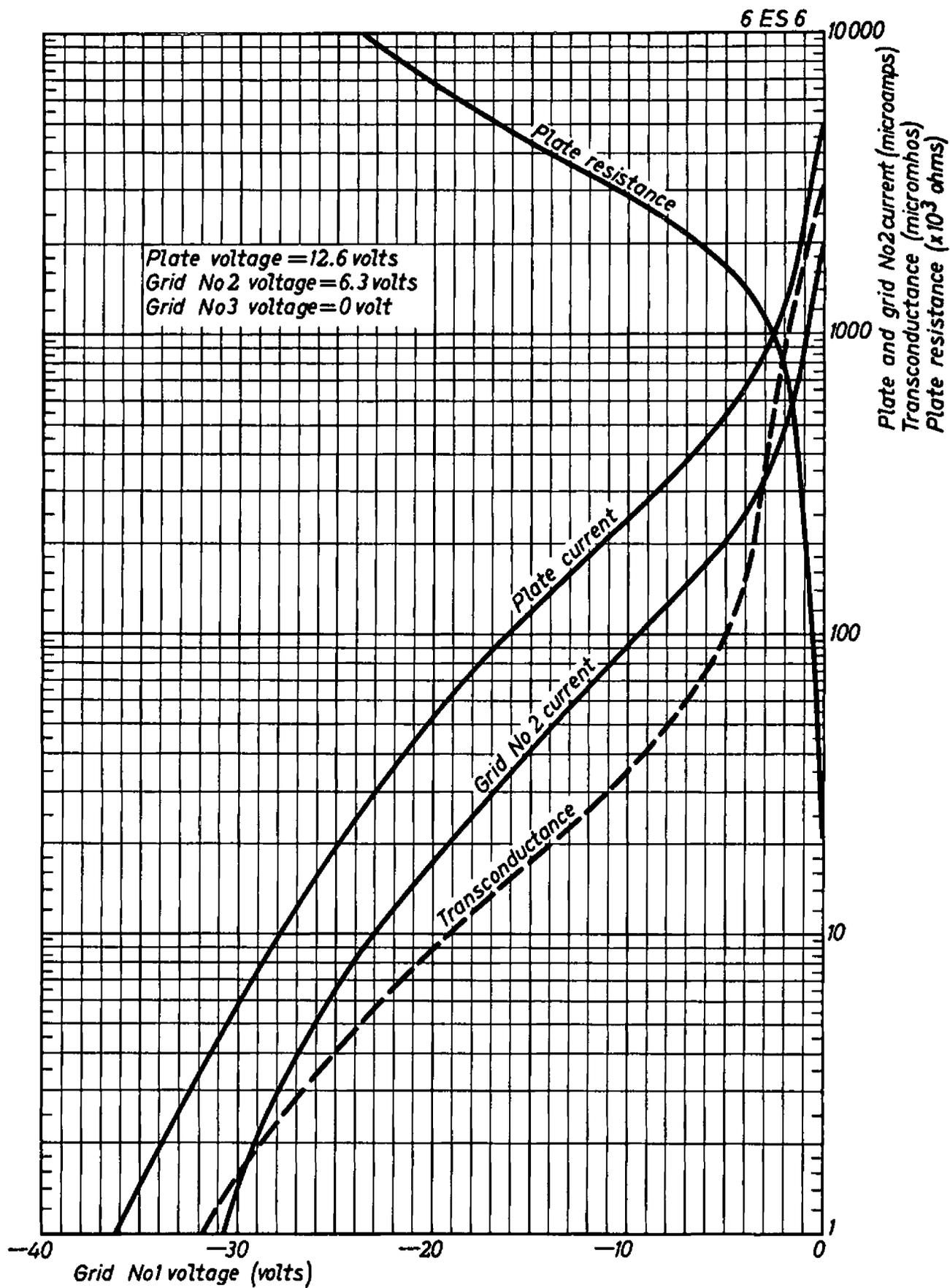
Operating characteristics as R.F. or I.F. amplifier

Plate voltage	25	12.6	6.3	12.6	6.3 volts
Grid No. 2 voltage	6.3	6.3	3.2	3.2	1.6 volts
Grid No. 3 voltage	0	0	0	0	0 volt
Grid No. 1 bias <sup>1)</sup>	-0.7	-0.7	-0.7	-0.7	-0.7 volt
Plate current	3.3	3	1	1	0.4 mamps
Grid No. 2 current	0.95	1.1	0.4	0.35	0.15 mamps
Transconductance	2100	1900	1000	1100	500 micromhos
Transconductance reduced to 1/10 at grid No.1 bias of	-3.5	-3.5	-2.5	-2.5	-2.5 volts
Transconductance reduced to 1/20 at grid No.1 bias of	-5	-5	-4	-4	-3.5 volts
Plate resistance	0.05	0.15	0.07	0.2	0.2 megohm
Equivalent noise resistance	5000	5500	8000	7000	15000 ohms

Operating characteristics as mixer (R.F. voltage applied to grid No. 1, oscillator voltage applied to grid No. 3)

Plate voltage	25	12.6	6.3 volts
Grid No. 2 voltage	6.3	6.3	3.2 volts
Grid No. 3 resistance	0.1	0.1	0.1 megohm
Oscillator voltage	10	10	5 volts (rms)
Grid No. 1 bias <sup>1)</sup>			
Plate current	1.8	1.3	0.45 mamps
Grid No. 2 current	1.5	1.7	0.6 mamps
Conversion conductance	600	550	300 micromhos
Conversion conductance reduced to 1/10 at grid No. 1 bias of	-3	-3.5	-2.5 volts
Conversion conductance reduced to 1/20 at grid No. 1 bias of	-4	-5	-3.5 volts
Plate resistance	50000	25000	30000 ohms
Equivalent noise resistance	40000	40000	55000 ohms

<sup>1)</sup> Grid No. 1 bias obtained by grid current biasing with grid No. 1 resistor of 10 megohms



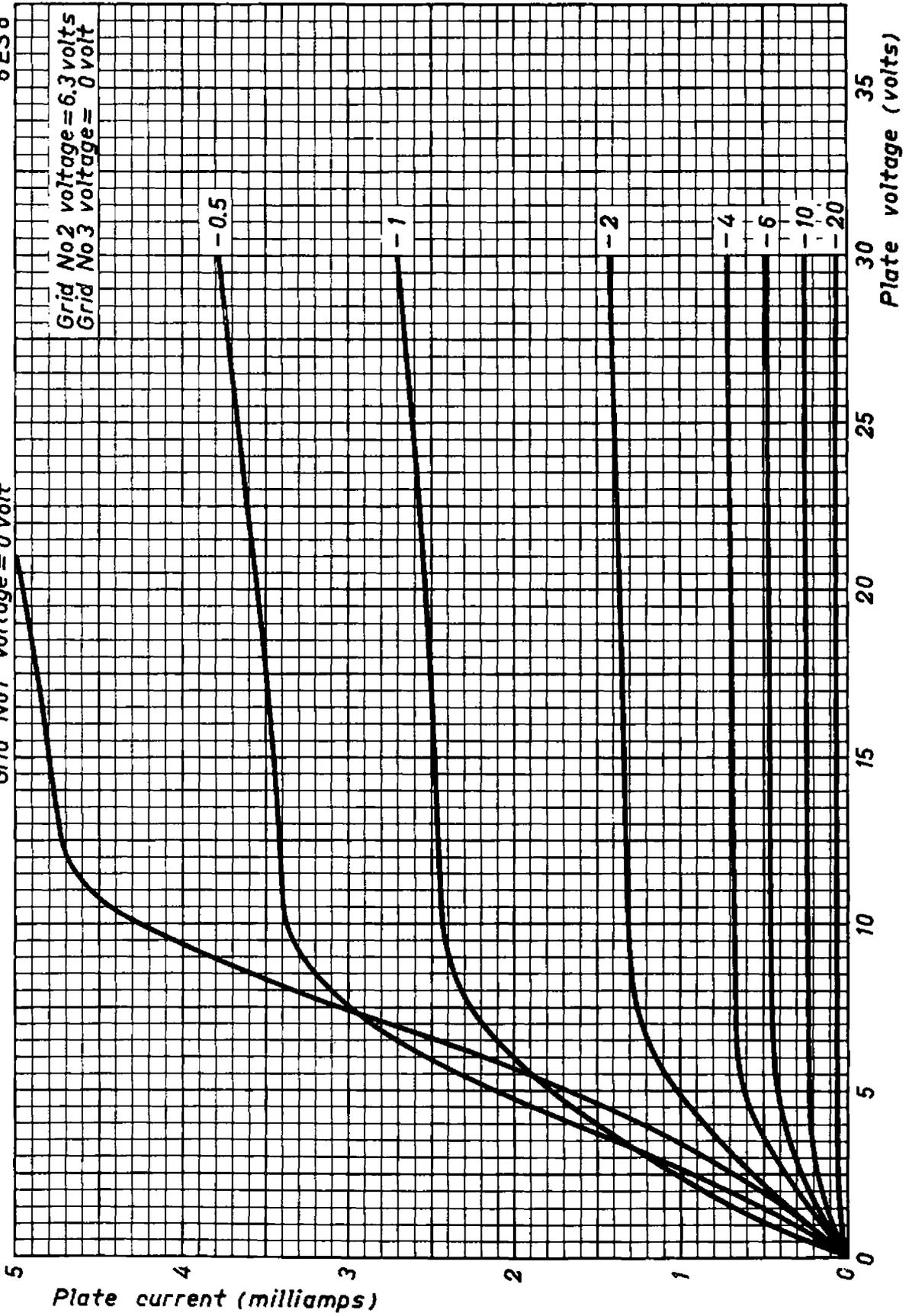
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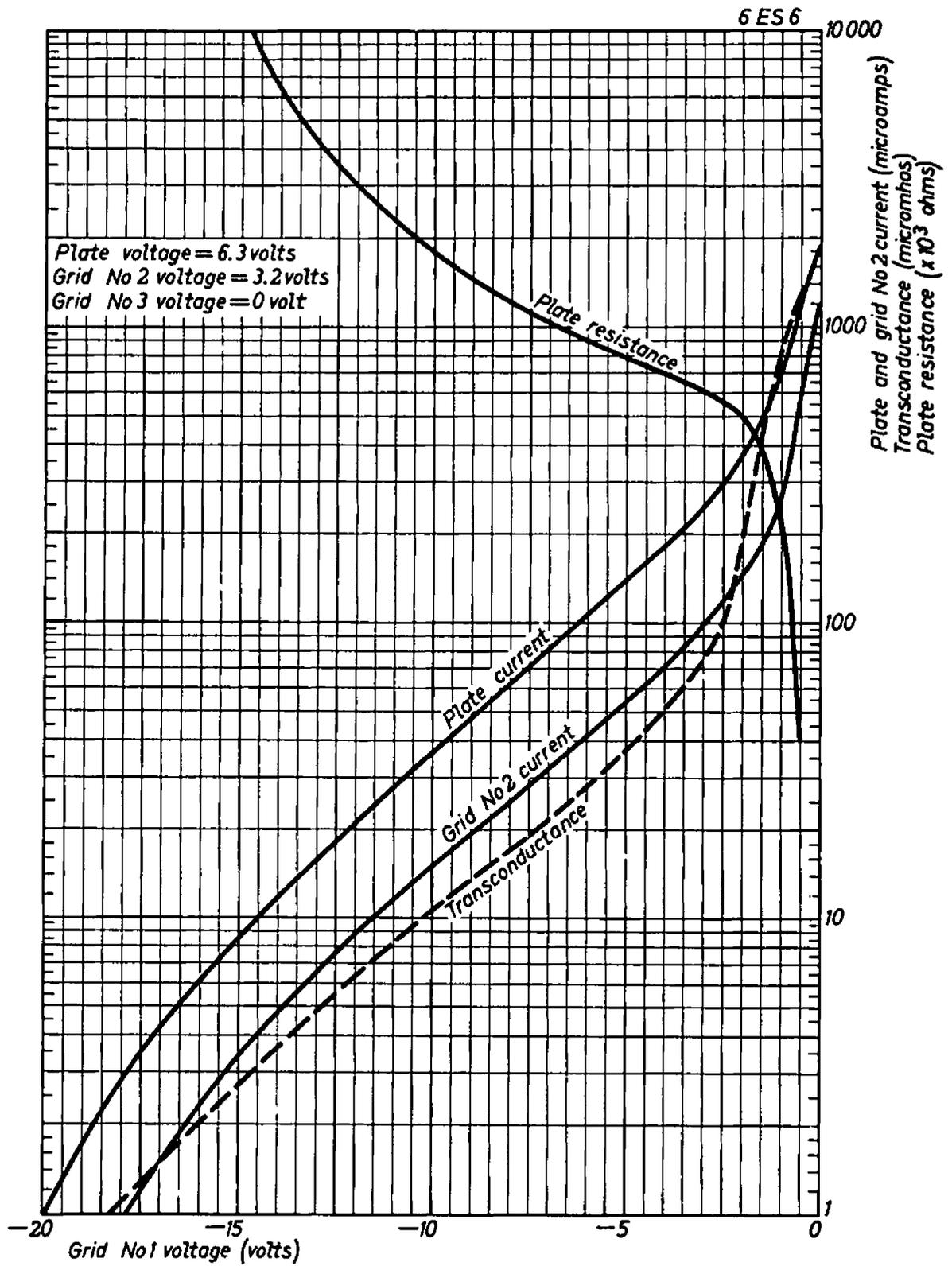
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Grid No 1 voltage = 0 volt

Grid No 2 voltage = 6.3 volts  
Grid No 3 voltage = 0 volt

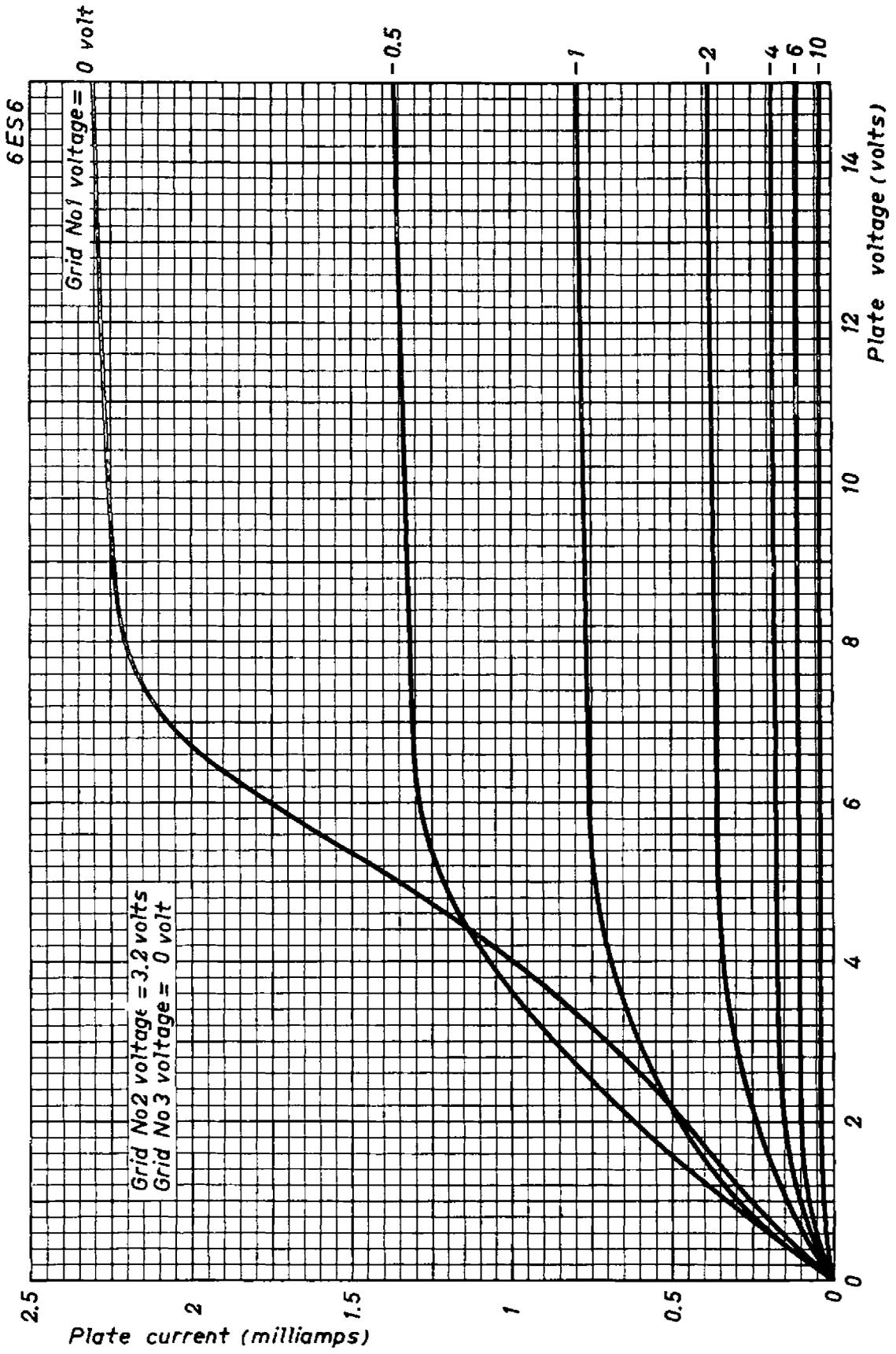


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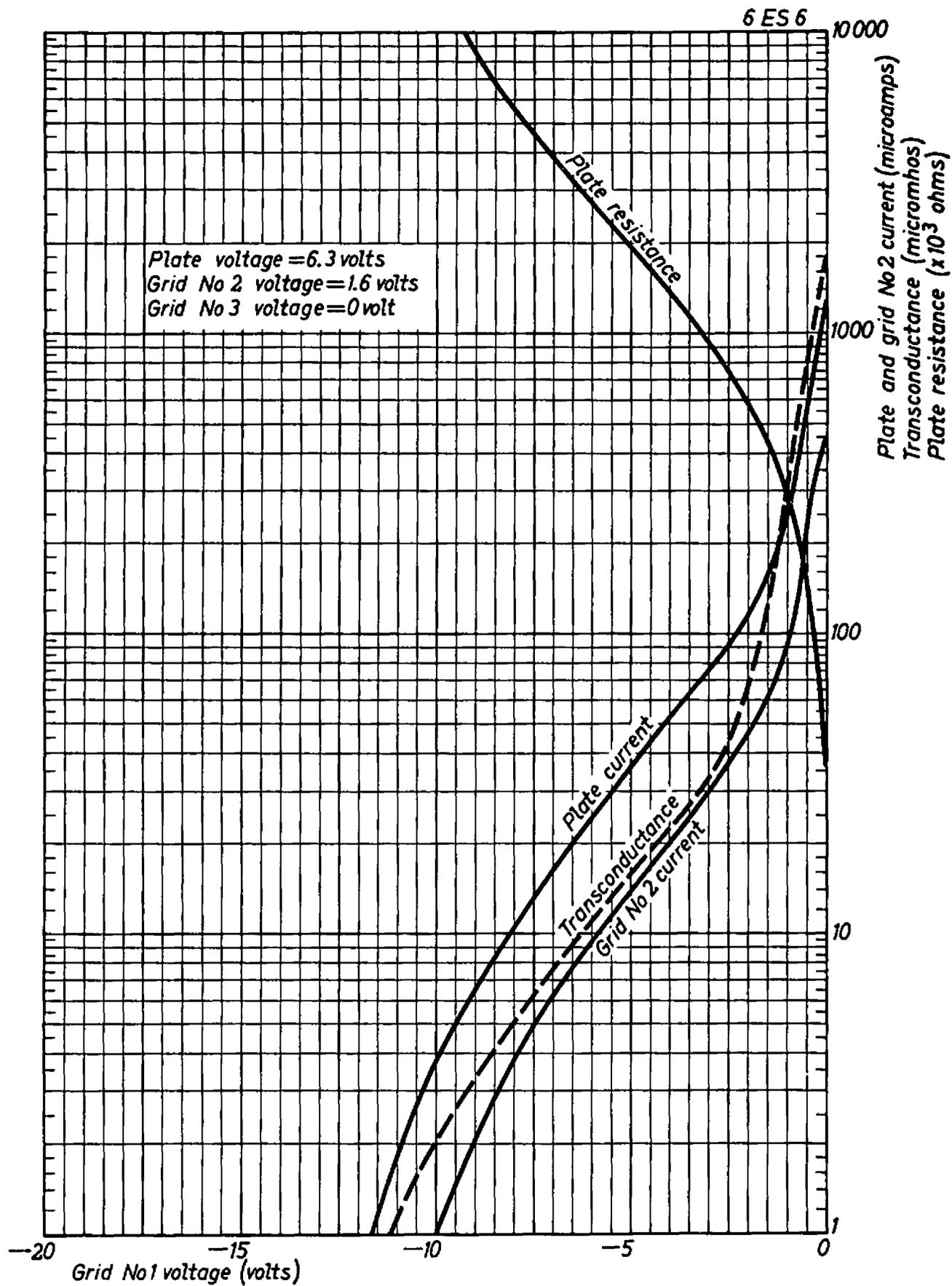


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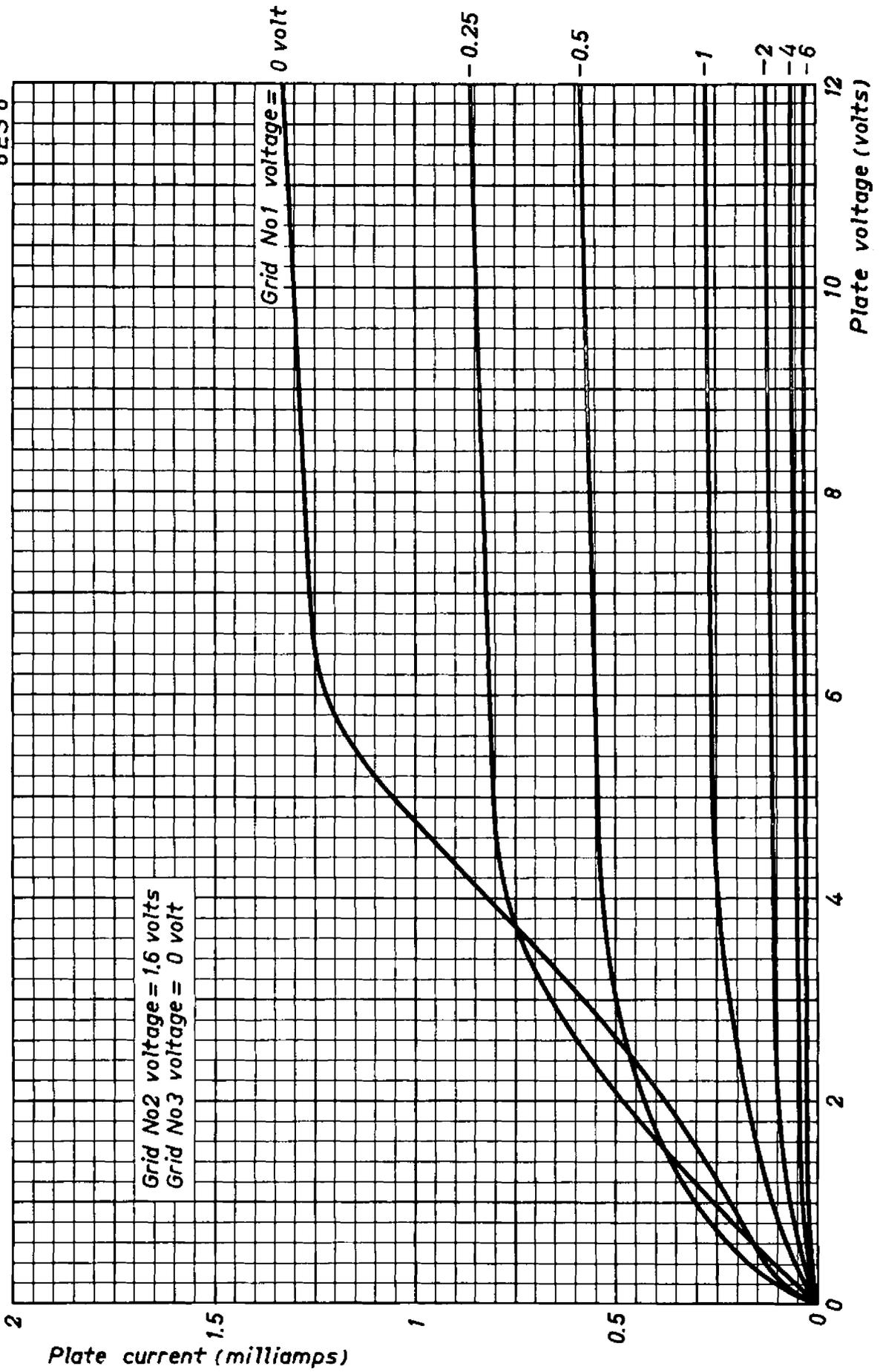
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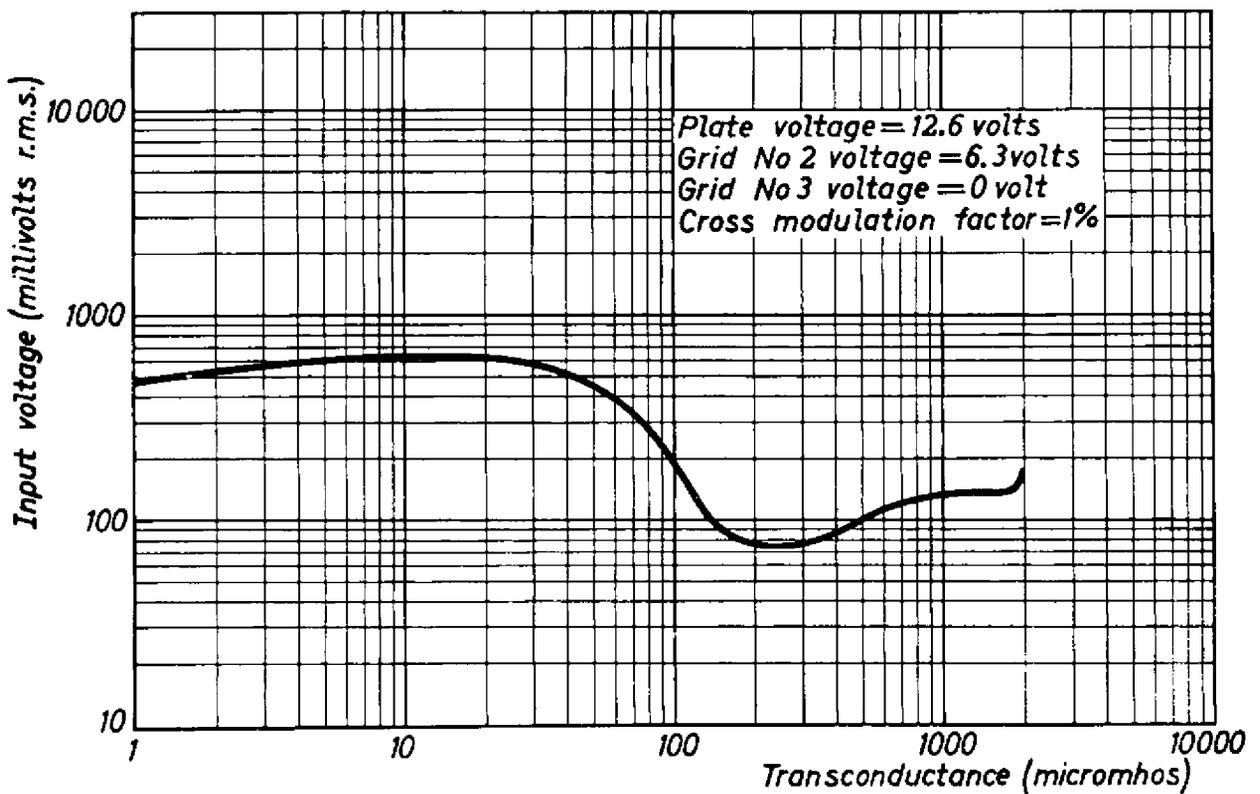
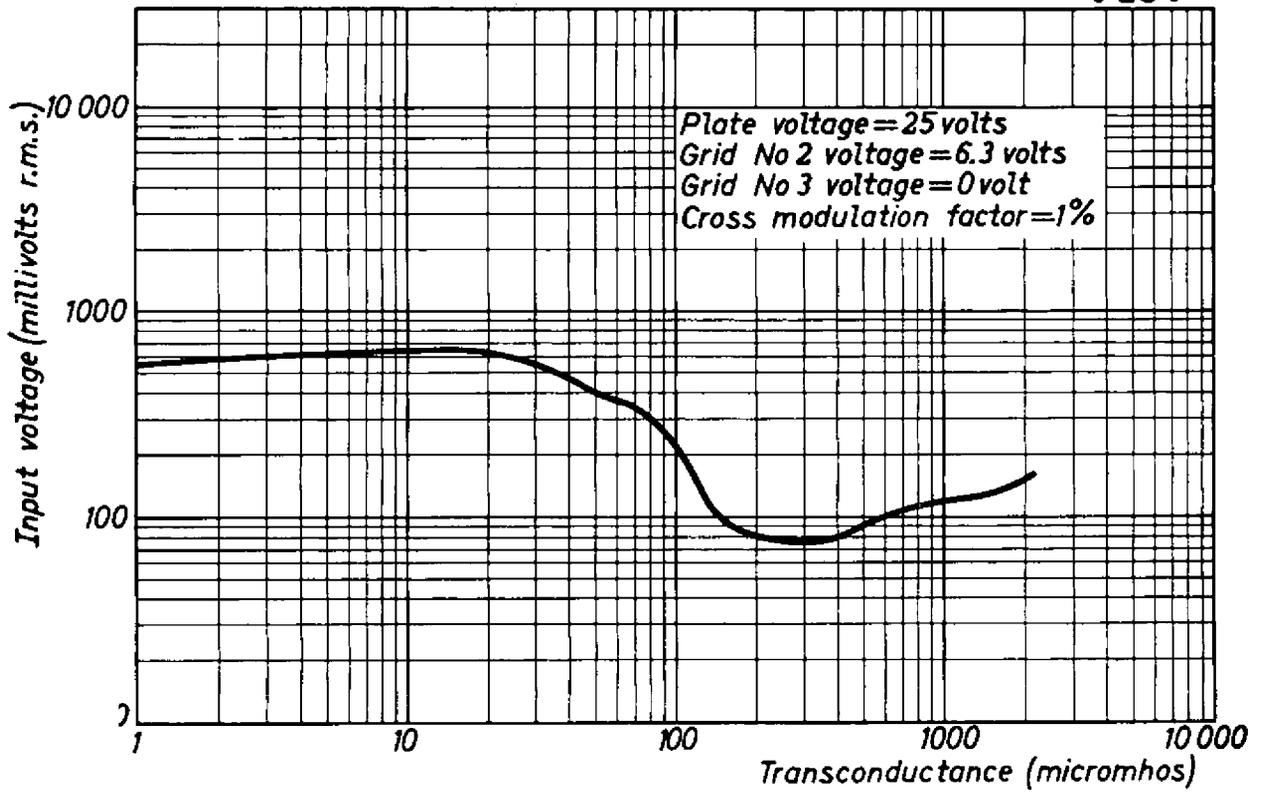


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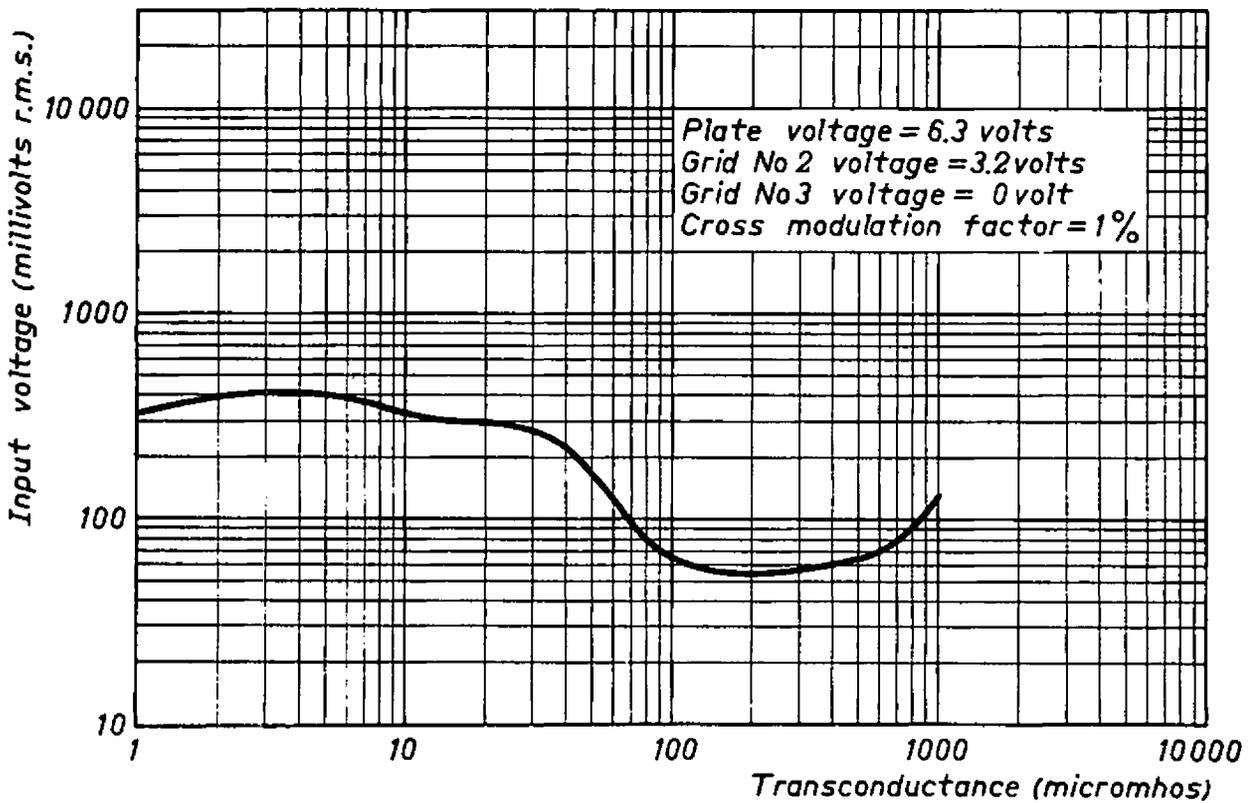
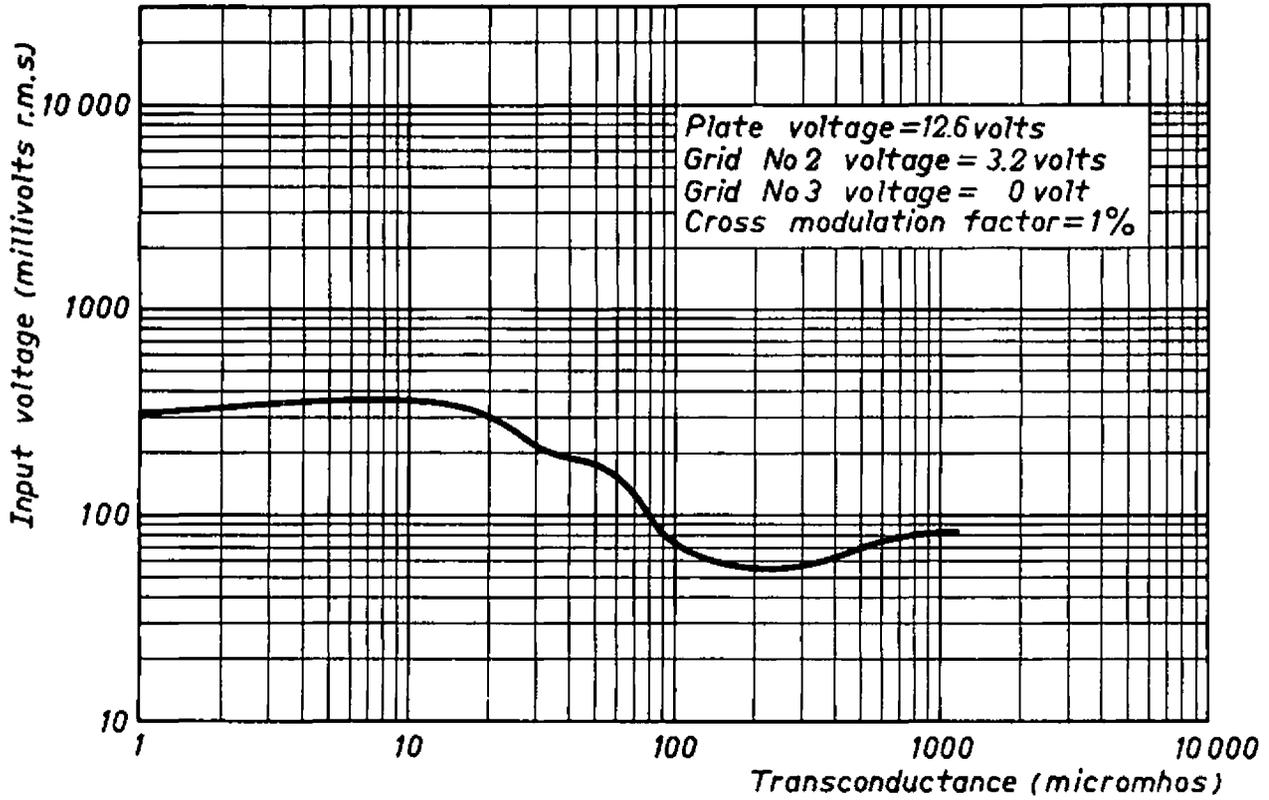
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